



GLASS PASSIVATED SILICON RECTIFIER

BY251G THRU BY255G

VOLTAGE RANGE
CURRENT

200 to 1300 Volts
3.0 Ampere

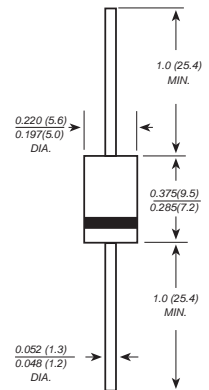
FEATURES

- The plastic package carries Underwriters Laboratory
- Flammability Classification 94V-0
- Construction utilizes void-free
- molded plastic technique
- Low reverse leakage
- High forward surge current capability
- High temperature soldering guaranteed:
250°C/10 seconds, 0.375" (9.5mm) lead length,
5 lbs. (2.3kg) tension

MECHANICAL DATA

- Case : JEDEC DO-201AD molded plastic body
- Terminals : Plated axial leads, solderable per MIL-STD-750, Method 2026
- Polarity : Color band denotes cathode end
- Mounting Position : Any
- Weight : 0.04 ounce, 1.10 grams

DO-201AD



Dimensions in inches and (millimeters)

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

- Ratings at 25°C ambient temperature unless otherwise specified.
- Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

	SYMBOLS	BY251G	BY252G	BY253G	BY254G	BY255G	UNITS
Maximum repetitive peak reverse voltage	V_{RRM}	200	400	600	800	1300	VOLTS
Maximum RMS voltage	V_{RMS}	140	280	420	560	910	VOLTS
Maximum DC blocking voltage	V_{DC}	200	400	600	800	1300	VOLTS
Maximum average forward rectified current 0.375" (9.5mm) lead length at $T_A=75^\circ\text{C}$	$I_{(AV)}$	3.0					Amps
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method)	I_{FSM}	150					Amps
Maximum instantaneous forward voltage at 3.0A	V_F	1.1					Volts
Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$	I_R	10.0 500					μA
Typical junction capacitance (NOTE 1)	C_J	30.0					pF
Typical thermal resistance (NOTE 2)	$R_{\theta JA}$	20.0					$^\circ\text{C/W}$
Operating junction and storage temperature range	T_J, T_{STG}	-65 to +175					$^\circ\text{C}$

Note: 1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. Thermal resistance from junction to ambient at 0.375" (9.5mm) lead length, P.C.B. mounted



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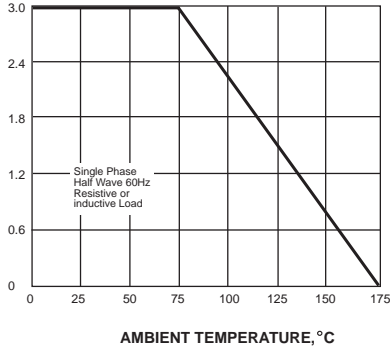
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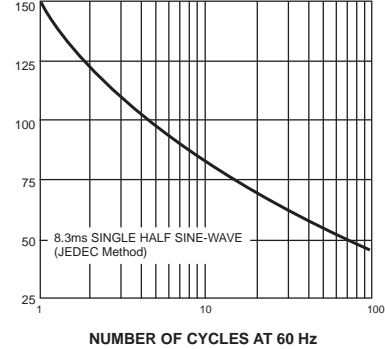
AVERAGE FORWARD RECTIFIED CURRENT,
AMPERES

FIG. 1- FORWARD CURRENT DERATING CURVE



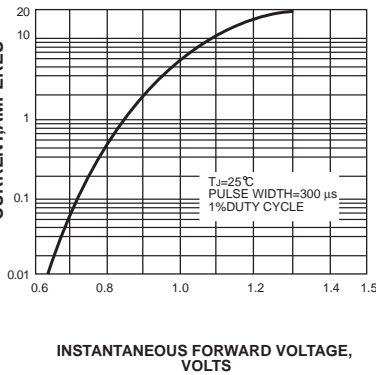
PEAK FORWARD SURGE CURRENT,
AMPERES

FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT



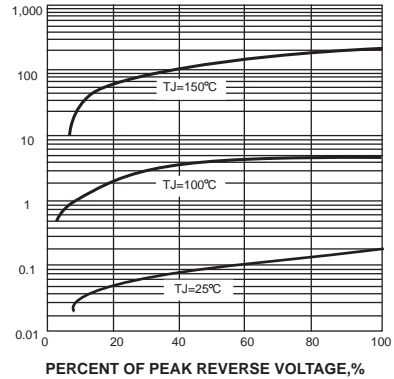
INSTANTANEOUS FORWARD CURRENT, AMPERES

FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



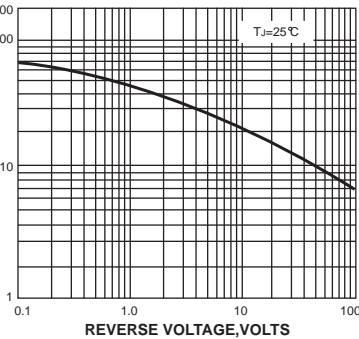
INSTANTANEOUS REVERSE CURRENT,
MICROAMPERES

FIG. 4-TYPICAL REVERSE CHARACTERISTICS



JUNCTION CAPACITANCE, pF

FIG. 5-TYPICAL JUNCTION CAPACITANCE



TRANSIENT THERMAL IMPEDANCE,
°C/W

FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

